

Novel insights into the unique intrinsic sensing behaviors of 2D nanomaterials for volatile organic compounds: from graphene to MoS₂ and black phosphorous

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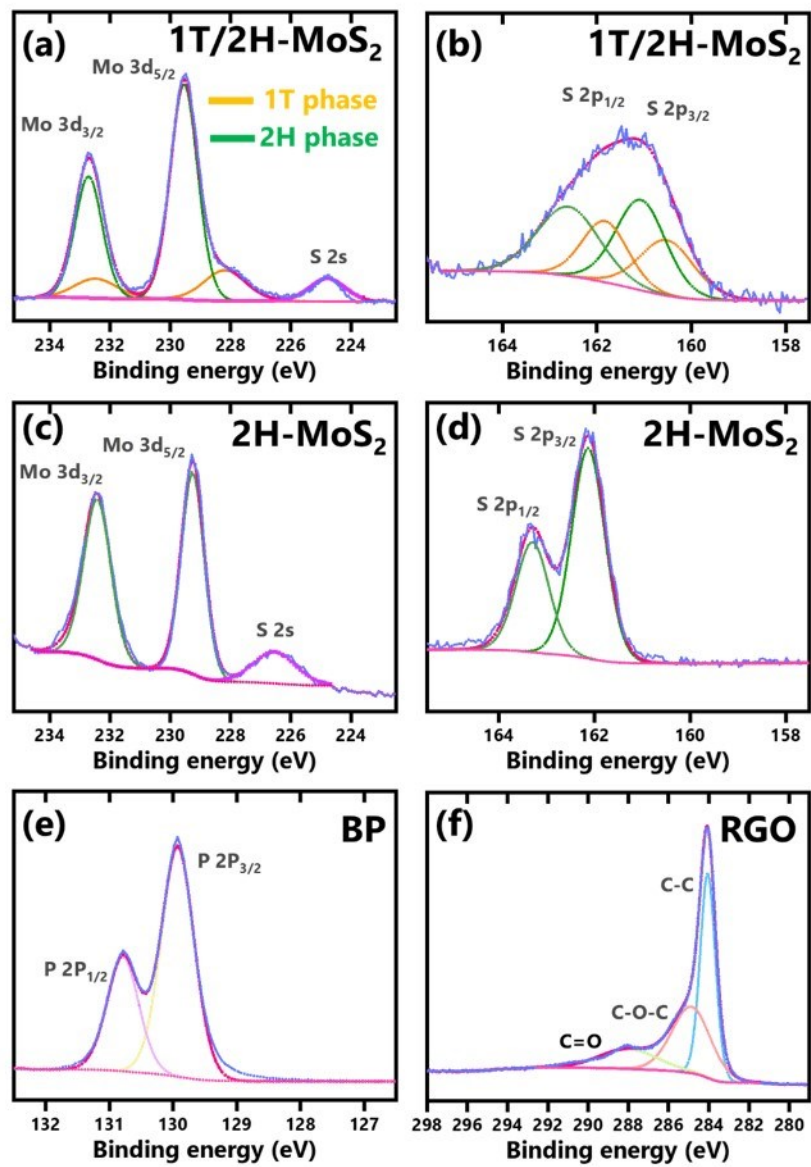


Figure S1 XPS spectra of (a)-(b) 1T/2H-MoS₂, (c)- (d) 2H-MoS₂, (e) BP, and (f) RGO. The orange and green line represents 1T and 2H phase of MoS₂, respectively.

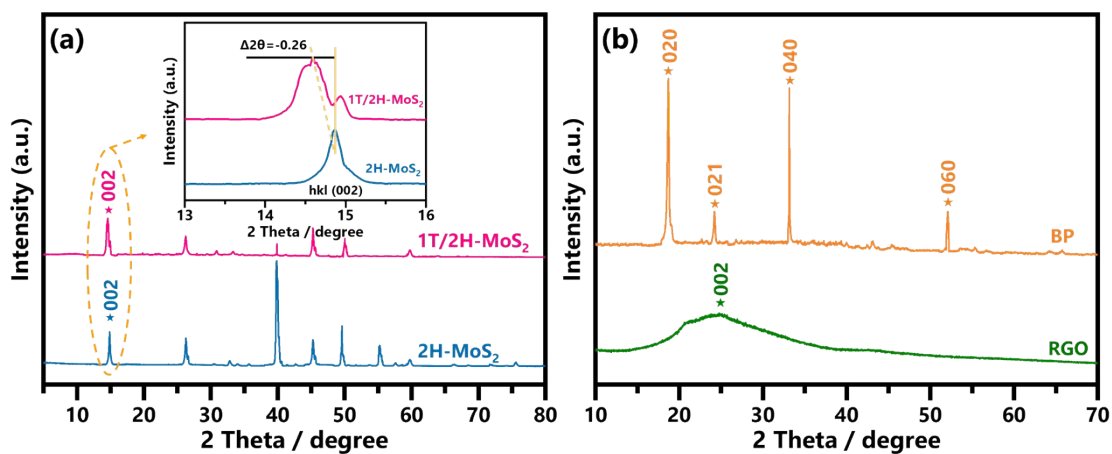


Figure S2 XRD patterns of (a) 1T/2H-MoS₂ and 2H-MoS₂, and (b) BP and RGO.

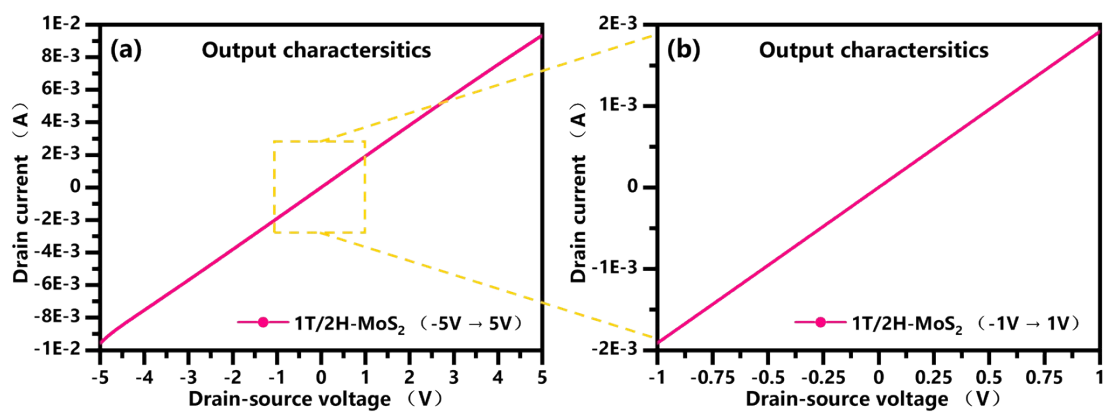


Figure S3 Drain current (I_{ds}) vs. source-drain voltage (V_{ds}) for 1T/2H-MoS₂ with a voltage range of (a) -5 V to +5 V and (b) -1 V to +1 V, respectively.

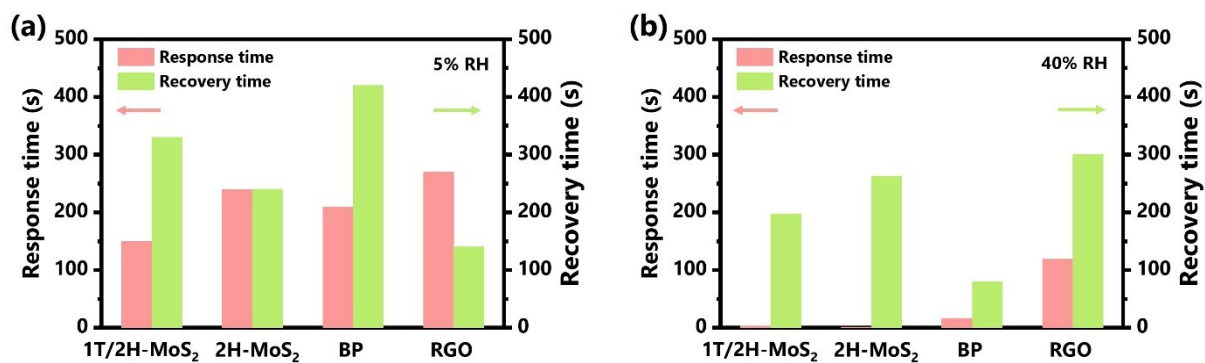


Figure S4 Comparison of response and recovery times of 1T/2H-MoS₂, 2H-MoS₂, BP, and RGO sensor toward 1 ppm HCHO in dry air and under 40% RH.

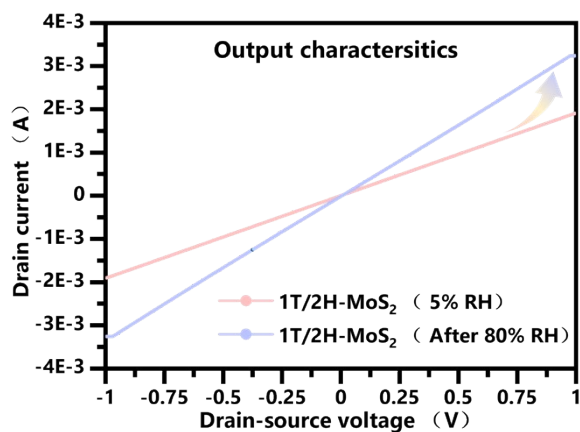


Figure S5 The I_{ds} - V_{ds} of 1T/2H-MoS₂ before and after sensing tests under humidity condition.

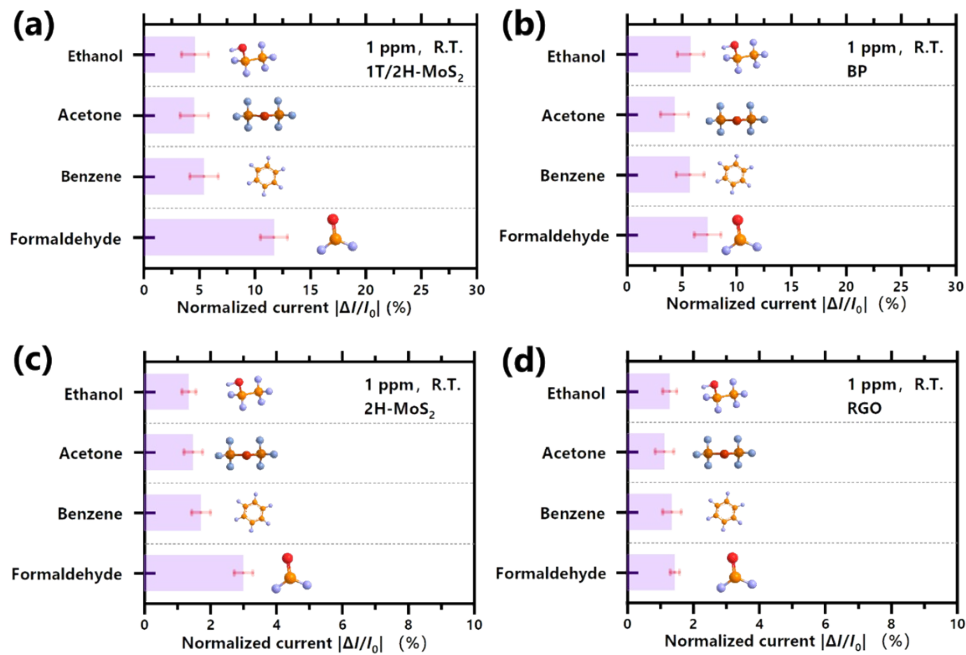


Figure S6 Relative responses of the (a) 1T/2H-MoS₂, (b) BP, (c) 2H-MoS₂ and (d) RGO FET sensors to different VOCs at 1 ppm.

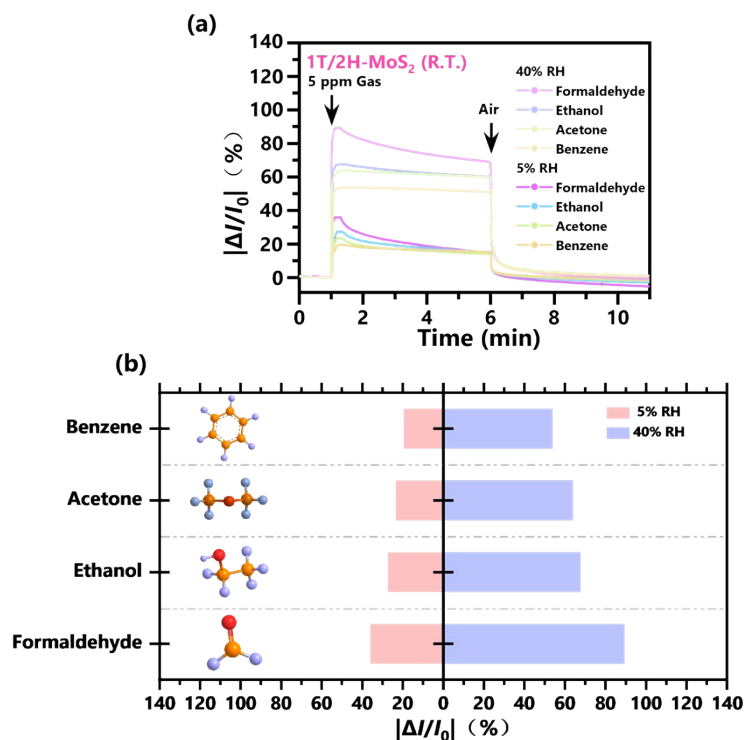
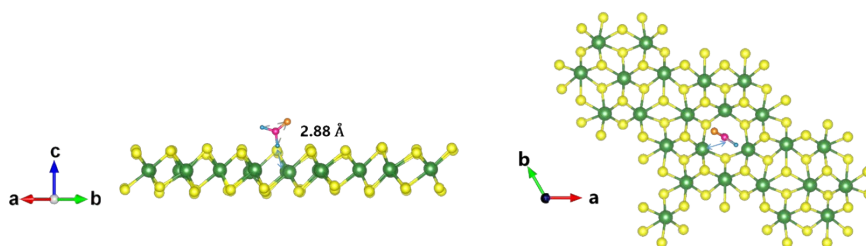
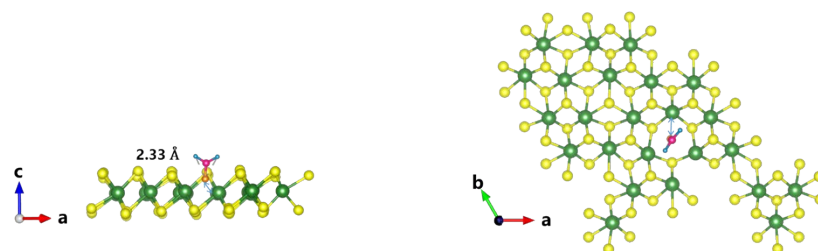


Figure S7 (a) Gas sensing responses and (b) relative responses of 1T/2H-MoS₂ sensor to different VOCs at 5 ppm under 5% and 40% RH.

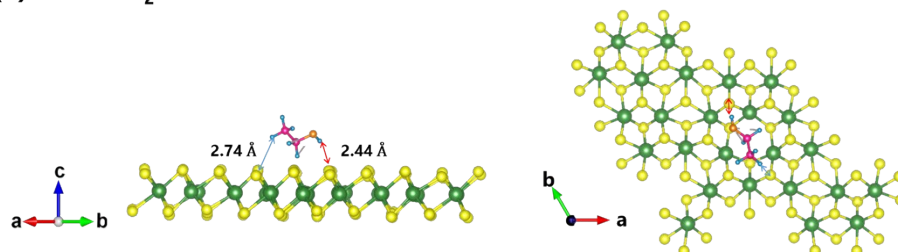
(a) 1T-MoS₂ → Formaldehyde - H terminate



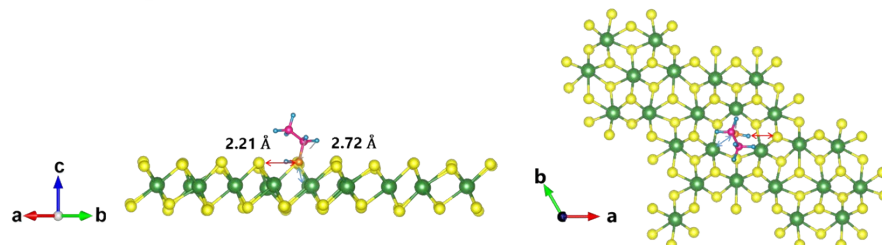
(b) 1T-MoS₂ → Formaldehyde - O terminate



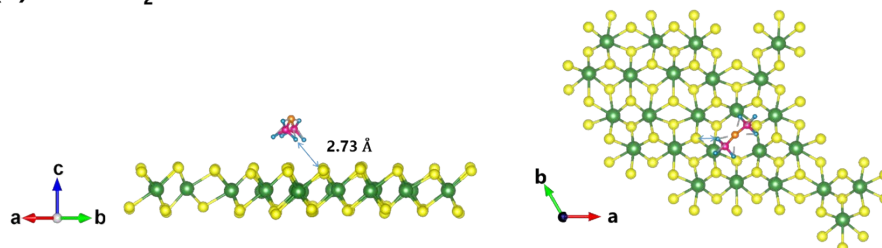
(c) 1T-MoS₂ → Ethanol - H terminate



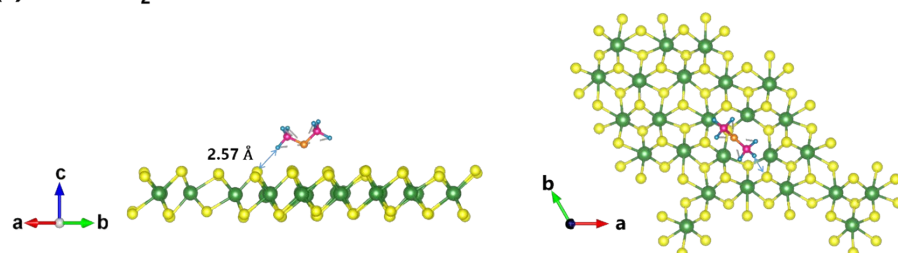
(d) 1T-MoS₂ → Ethanol - O terminate



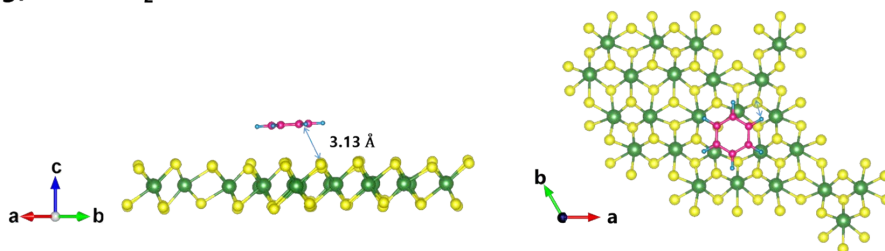
(e) 1T-MoS₂ → Acetone - H terminate



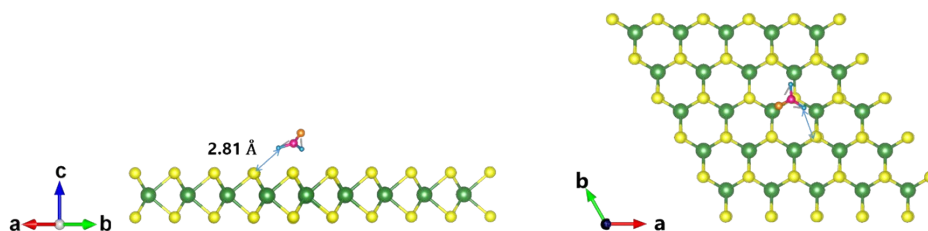
(f) 1T-MoS₂ → Acetone - O terminate



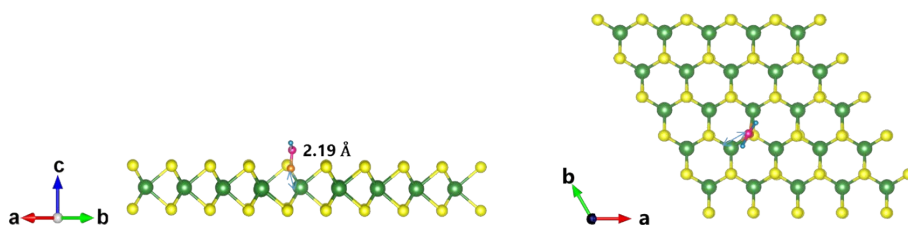
(g) 1T-MoS₂ → Benzene - H terminate



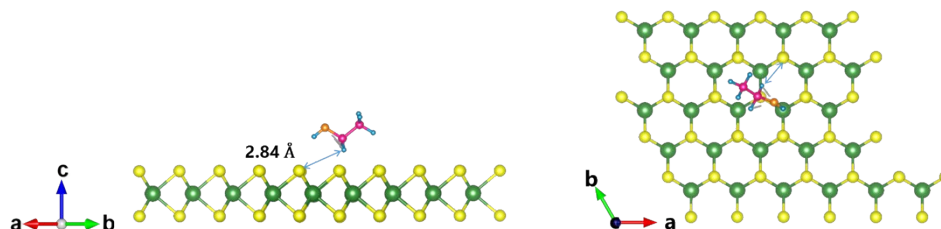
(h) 2H-MoS₂ → Formaldehyde - H terminate



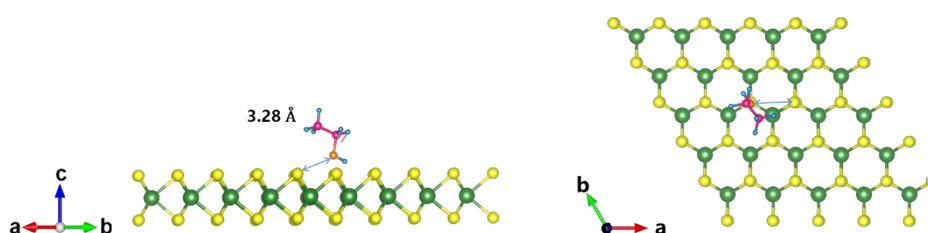
(i) 2H-MoS₂ → Formaldehyde - O terminate



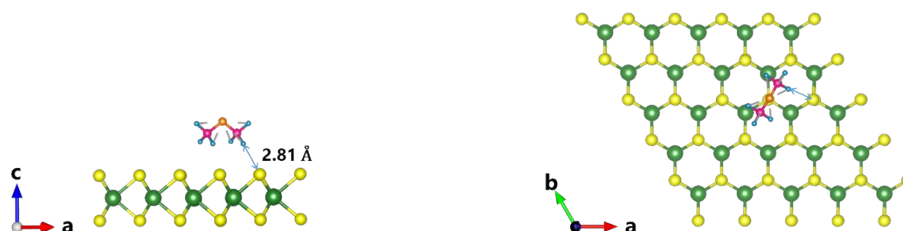
(j) 2H-MoS₂ → Ethanol - H terminate



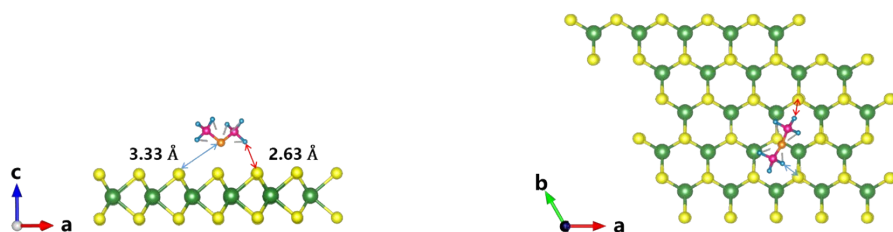
(k) 2H-MoS₂ → Ethanol - O terminate



(l) 2H-MoS₂ → Acetone - H terminate



(m) 2H-MoS₂ → Acetone - O terminate



(n) 2H-MoS₂ → Benzene - H terminate

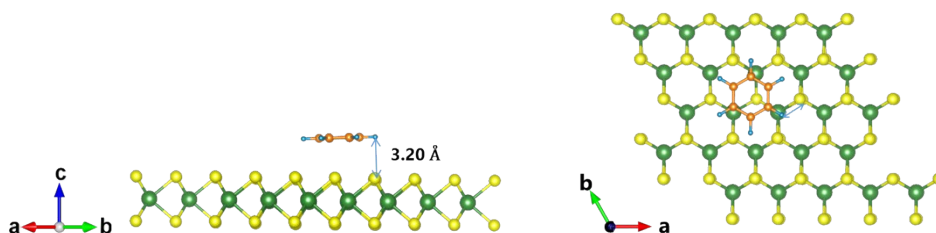
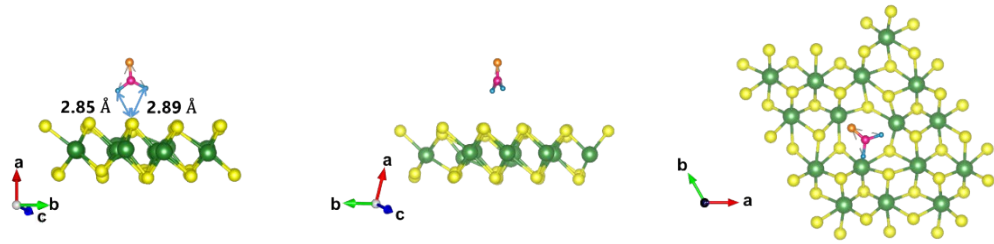


Figure S8 Configurations of (a, b) formaldehyde, (c, d) ethanol, (e, f) acetone, (g, h) benzene gas molecule adsorbed with H terminate and O terminate, respectively, at the sulfur vacancy of 1T-MoS₂. Configurations of (h, i) formaldehyde, (j, k) ethanol, (l, m) acetone, (n) benzene gas molecule adsorbed with H terminate and O terminate, respectively, at the sulfur vacancy of 2H-MoS₂.

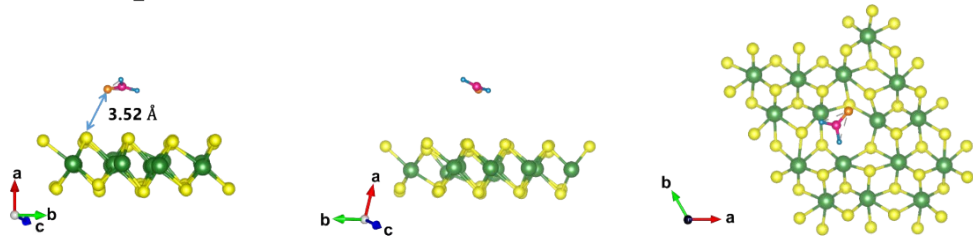
Table S1 DFT calculation results of adsorption energy (eV) of formaldehyde, ethanol, acetone, benzene molecule with H atom or O atom as terminate on sulfur vacancy site on 1T-MoS₂ and 2H-MoS₂. The “H” and “O” refer to the bonding approaches for analyte molecule adsorbed at the S vacancy that rely on H or O atom, respectively.

Channel	Formaldehyde-	Formaldehyde-	Ethanol-	Ethanol-	Acetone-	Acetone-	Benzene-
	H	O	H	O	H	O	H
1T-MoS ₂	-0.744	-1.645	-0.846	-1.213	-0.715	-0.778	-0.954
2H-MoS ₂	-0.287	-0.557	-0.381	-0.386	-0.325	-0.329	-0.568

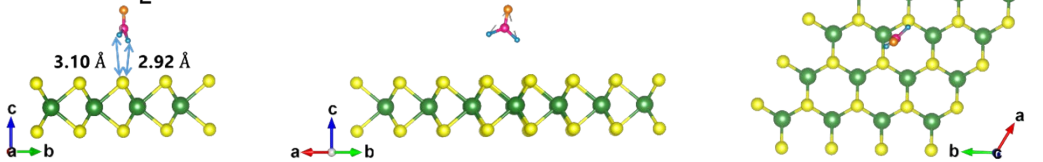
(a) 1T-MoS₂-H terminate



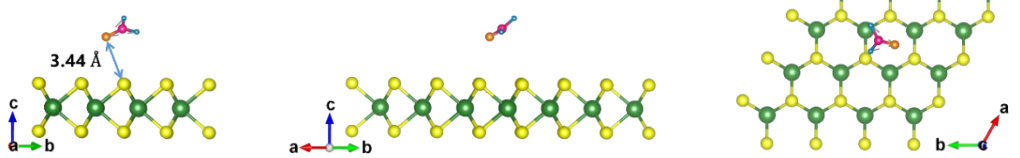
(b) 1T-MoS₂-O terminate



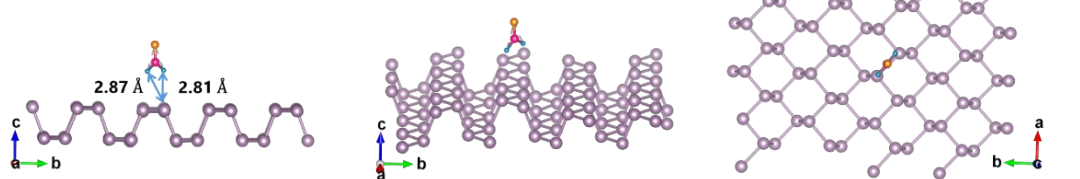
(c) 2H-MoS₂-H terminate



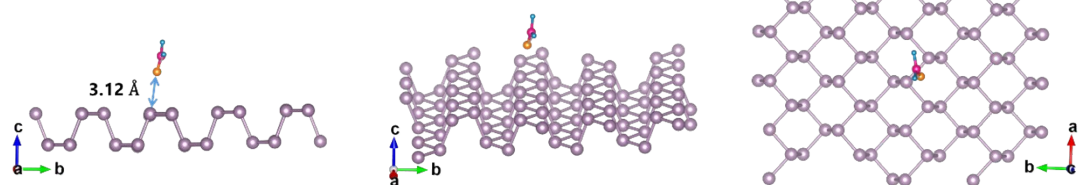
(d) 2H-MoS₂-O terminate



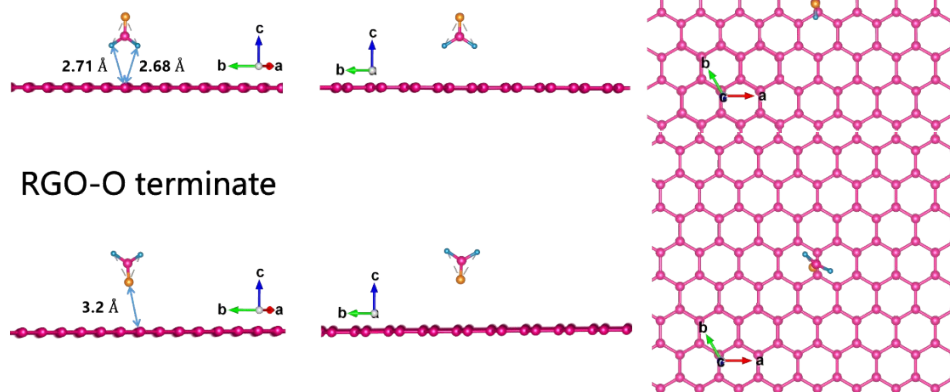
(e) BP-H terminate



(f) BP-O terminate



(g) RGO-H terminate



(h) RGO-O terminate

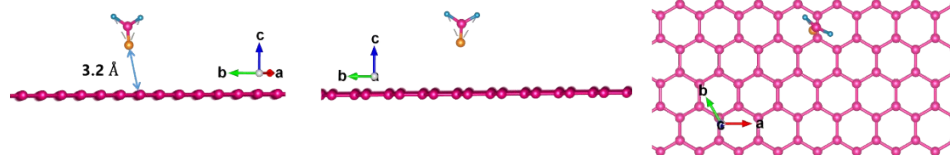
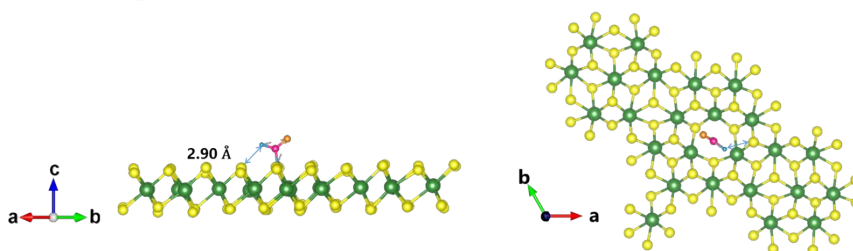
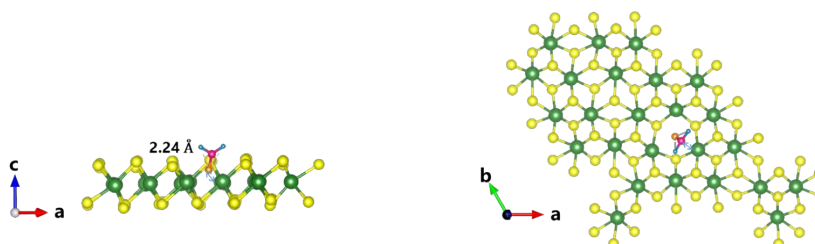


Figure S9 Configurations of HCHO molecule adsorbed with H atoms as terminate at the basal plane of (a) 1T-MoS₂, (c) 2H-MoS₂, (e) BP, (g) RGO, and with O atom as terminate at the basal plane of (b) 1T-MoS₂, (d) 2H-MoS₂, (f) BP, (h) RGO.

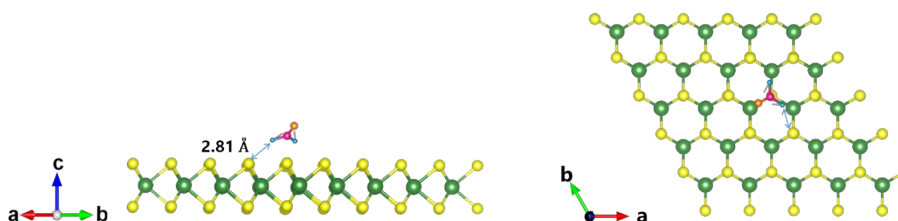
(a) 1T-MoS₂ → Formaldehyde - H terminate (Humidity)



(b) 1T-MoS₂ → Formaldehyde - O terminate (Humidity)



(c) 2H-MoS₂ → Formaldehyde - H terminate (Humidity)



(d) 2H-MoS₂ → Formaldehyde - O terminate (Humidity)

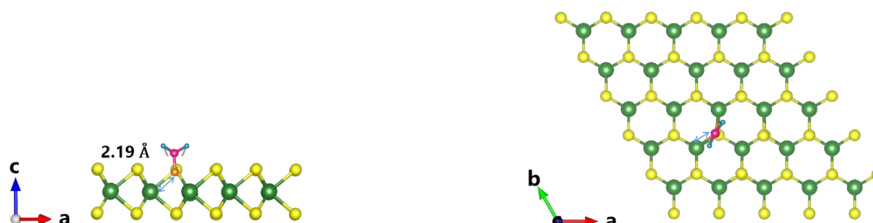


Figure S10 Configurations of formaldehyde molecule adsorbed with H atoms as terminate at the sulfur vacancy of (a) 1T-MoS₂, (c) 2H-MoS₂; and with O atoms as terminate at the sulfur vacancy of (b) 1T-MoS₂, (d) 2H-MoS₂ under humidity condition.

Table S2 DFT calculation results of adsorption energy (eV) of formaldehyde molecule with H atom or O atom as terminate, respectively, on sulfur vacancy sites on 1T-MoS₂ and 2H-MoS₂ under humidity condition. The “H” and “O” refer to the bonding approaches for analyte molecule adsorbed at the S vacancy that rely on H or O atom, respectively.

Channel	Formaldehyde-H (humidity)	Formaldehyde-O (humidity)
1T-MoS₂	-0.864	-1.917
2H-MoS₂	-0.426	-0.609